



GaN FET Technology

120 Watt Series

Small Size Desktop Type

ATS120TS - P X X X

P : C6 / C14 ← → O / P Voltage

Features :

- IEC/EN/UL 62368-1 3rd Edition
- 100-240 VAC Universal Input
- Gallium Nitride Based Design
- High Power Density : 9.1W / in³
- With 200kHz Switching Frequency
- Efficiency up to 94%
- Regulated Output with Low Ripple Noise
- Modified and Custom Design Available
- 1 Year Warranty

Output

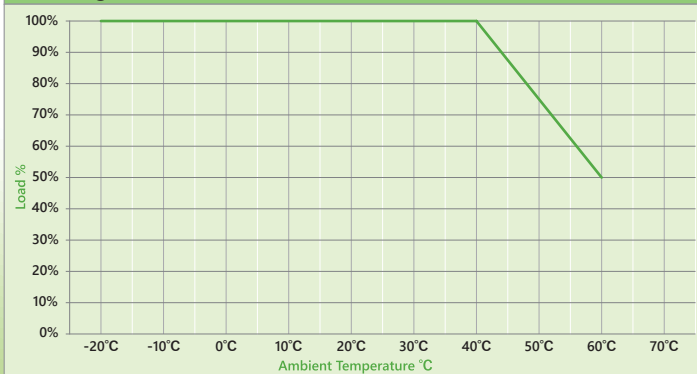
Load Regulation	±5% (Typical)
Ripple & Noise	≤ 1% Vp-p @ Full Load
Transient (Dynamic) Response	0.5mS with 50% Load Change
Start-up Time	< 3,000mS
Hold-up Time	≥ 10mS @ Full Load
Rise Time	< 50mS
Protection	Short Circuit Protection / Over Voltage Protection / Over Current Protection / Over Temperature Protection

Model	O/P Voltage	O/P Current	Watt
ATS120TS-P120	12.0V	9.00A	108W
ATS120TS-P190	19.0V	6.30A	120W
ATS120TS-P200	20.0V	6.00A	120W
ATS120TS-P240	24.0V	5.00A	120W
ATS120TS-P480	48.0V	2.50A	120W
ATS120TS-P560	56.0V	2.14A	120W

Input

Voltage	100-240VAC
Line Frequency	50-60Hz
Current	1.6A Max.
Protection	Internal Primary Current Fuse
Configuration	IEC60320/C6, C14

Derating Curve



Electrical

Topology	LLC
Dielectric Withstand	3,000VAC Primary - Secondary
Earth Leakage Current	< 5mA
Efficiency	DoE Level VI, ErP Stage 2, CoC Tier 2
EMC Standards	EN55032
	EN61000-3-2,3
	EN55035
MTBF	300,000 Calculated Hours at 25°C , by Telcordia SR-332

Environmental

Operating Temperature	-20 to + 40°C
Storage Temperature	-20 to + 80°C
Operating Altitude	5,000M
Relative Humidity	Operating : 20 to 80% RH
	Storage : 10 to 90% RH
Cooling	Natural Convection Cooling

Mechanical

Case Dimension	L 132 × W 51 × H 32 (mm)
Weight	336g (Ref.)